Features

- Low power consumption
- Low voltage drop
- Low temperature coefficient
- High input voltage (up to 32V)
- Output voltage accuracy: tolerance ±3%
- TO92 and SOT89 package

Applications

- Battery-powered equipment
- Communication equipment
- Audio/Video equipment

General Description

The TX75XXH series is a set of three-terminal low power high voltage regulators implemented in CMOS technology. They allow input voltages as high as 32V. They are available with several fixed output voltages ranging from 2.5V to 5.0V. CMOS technology ensures low voltage drop and low quiescent current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain variable voltages and currents.

Selection Table

Part No.	Output Voltage	Package	Marking
TX7525Hxx	2.5V	TO92 SOT89	75XX-H#(for TO92) 75XX-H#(for SOT89)
TX7527Hxx	2.7V		
TX7530Hxx	3.0V		
TX7533Hxx	3.3V		
TX7536Hxx	3.6V		
TX7540Hxx	4.0V		
TX7544Hxx	4.4V		
TX7550Hxx	5.0V		

Note:"XX" stands for output voltages.

TO92 & SOT89 packages will add a "#" mark at the end of the marking.

Order Information

TX75①②③④⑤

Designator	Symbol	Description
① ②	Integer	Output Voltage(2.1~6.0V)
③	H	Standard
④	T	Package:TO-92
	P	Package:SOT89
⑤	R	RoHS / Pb Free
	G	Halogen Free

Block Diagram

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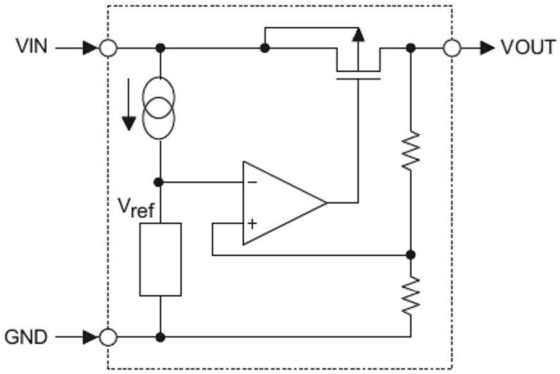
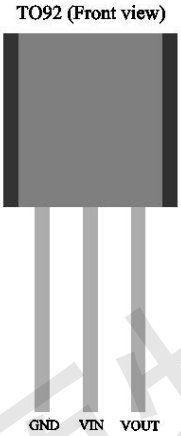
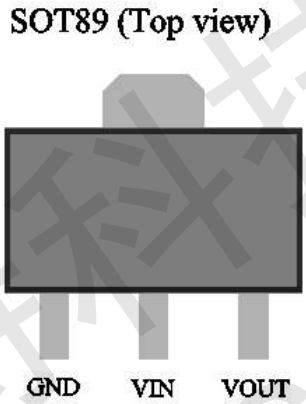


Pin Assignment





Absolute Maximum Ratings

Supply Voltage .....-0.3V to 32V Storage Temperature .....-50℃ to 125℃

Operating Temperature .....-40℃ to 85℃

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Thermal Information

Symbol	Parameter	Package	Max.	Unit
θ_{JA}	Thermal Resistance (Junction to Ambient) (Assume no ambient airflow, no heat sink)	TO92	200	℃/W
		SOT89	200	℃/W
P_D	Power Dissipation	TO92	0.50	W
		SOT89	0.50	W

Note: P_D is measured at Ta= 25℃

Electrical Characteristics

TX7525Hxx, +2.5V Output Type

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Ur
		V_{IN}	Conditions				

V_{OUT}	Output Voltage	8V	I_{OUT}=10mA	2.425	2.500	2.575	V
I_{OUT}	Output Current	8V	-	70	-	-	mA
ΔV_{OUT}	Load Regulation	8V	1mA≤I_{OUT}≤20mA	-	60	100	mV
V_{DIF}	Voltage Drop(Note)	-	I_{OUT}=1mA, ΔV_{OUT}=2%	-	100	-	mV
ISS	Current Consumption	8V	No load	-	2.5	5.0	μA
$\frac{V_{OUT}}{V_{IN} \quad V_{OUT}}$	Line Regulation	-	3.5V≤V_{IN}≤24V I_{OUT}=1mA	-	0.2	-	%/V
V_{IN}	Input Voltage	-	-	-	-	32	V
$\frac{V_{OUT}}{Ta}$	Temperature Coefficient	8V	IOUT=10mA 0℃<Ta<70℃	-	±0.41	-	mV/℃

Note: Dropout voltage is defined as the input voltage minus the output voltage that produces a 2% change in the output voltage from the value at V_{IN} = V_{OUT}+2V with a fixed load.

TX7527Hxx, +2.7V Output Type

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V_{IN}	Conditions				
V_{OUT}	Output Voltage	8V	I_{OUT}=10mA	2.619	2.700	2.781	V
I_{OUT}	Output Current	8V	-	70	-	-	mA
ΔV_{OUT}	Load Regulation	8V	1mA≤I_{OUT}≤20mA	-	60	100	mV
V_{DIF}	Voltage Drop(Note)	-	I_{OUT}=1mA, ΔV_{OUT}=2%	-	100	-	mV
ISS	Current Consumption	8V	No load	-	2.5	5.0	μA
$\frac{V_{OUT}}{V_{IN} \quad V_{OUT}}$	Line Regulation	-	3.7V≤V_{IN}≤24V I_{OUT}=1mA	-	0.2	-	%/V
V_{IN}	Input Voltage	-	-	-	-	32	V
$\frac{V_{OUT}}{Ta}$	Temperature Coefficient	8V	IOUT=10mA 0℃<Ta<70℃	-	±0.43	-	mV/℃

Note: Dropout voltage is defined as the input voltage minus the output voltage that produces a 2% change in the output voltage from the value at V_{IN} = V_{OUT}+2V with a fixed load.

TX7530Hxx, +3.0V Output Type

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V_{IN}	Conditions				
V_{OUT}	Output Voltage	8V	I_{OUT}=10mA	2.91	3.00	3.09	V
I_{OUT}	Output Current	8V	-	80	-	-	m

ΔV_{OUT}	Load Regulation	8V	1mA≤I_{OUT}≤20mA	-	60	100	mV
V_{DIF}	Voltage Drop(Note)	-	I_{OUT}=1mA, ΔV_{OUT}=2%	-	100	-	mV
ISS	Current Consumption	8V	No load	-	2.5	5.0	μA
$\frac{V_{OUT}}{V_{IN}\ V_{OUT}}$	Line Regulation	-	4V≤V_{IN}≤24V I_{OUT}=1mA	-	0.2	-	%/V
V_{IN}	Input Voltage	-	-	-	-	32	V
$\frac{V_{OUT}}{Ta}$	Temperature Coefficient	8V	IOUT=10mA 0℃<Ta<70℃	-	±0.45	-	mV/℃

Note: Dropout voltage is defined as the input voltage minus the output voltage that produces a 2% change in the output voltage from the value at V_{IN} = V_{OUT}+2V with a fixed load.

TX7533Hxx, +3.3V Output Type

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V_{IN}	Conditions				
V_{OUT}	Output Voltage	8V	I_{OUT}=10mA	3.201	3.300	3.399	V
I_{OUT}	Output Current	8V	-	80	-	-	mA
ΔV_{OUT}	Load Regulation	8V	1mA≤I_{OUT}≤20mA	-	60	100	mV
V_{DIF}	Voltage Drop(Note)	-	I_{OUT}=1mA, ΔV_{OUT}=2%	-	100	-	mV
ISS	Current Consumption	8V	No load	-	2.5	5.0	μA
$\frac{V_{OUT}}{V_{IN}\ V_{OUT}}$	Line Regulation	-	4.5V≤V_{IN}≤24V I_{OUT}=1mA	-	0.2	-	%/V
V_{IN}	Input Voltage	-	-	-	-	32	V
$\frac{V_{OUT}}{Ta}$	Temperature Coefficient	8V	IOUT=10mA 0℃<Ta<70℃	-	±0.5	-	mV/℃

Note: Dropout voltage is defined as the input voltage minus the output voltage that produces a 2% change in the output voltage from the value at V_{IN} = V_{OUT}+2V with a fixed load.

TX7536Hxx, +3.6V Output Type

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V_{IN}	Conditions				
V_{OUT}	Output Voltage	8V	I_{OUT}=10mA	3.492	3.600	3.708	V
I_{OUT}	Output Current	8V	-	80	-	-	mA
ΔV_{OUT}	Load Regulation	8V	1mA≤I_{OUT}≤20mA	-	60	100	m

V_{DIF}	Voltage Drop(Note)	-	I_{OUT}=1mA, ΔV_{OUT}=2%	-	100	-	mV
ISS	Current Consumption	8V	No load	-	2.5	5.0	μA
$\frac{V_{OUT}}{V_{IN} \quad V_{OUT}}$	Line Regulation	-	4.6V≤V_{IN}≤24V I_{OUT}=1mA	-	0.2	-	%/V
V_{IN}	Input Voltage	-	-	-	-	32	V
$\frac{V_{OUT}}{Ta}$	Temperature Coefficient	8V	IOUT=10mA 0℃<Ta<70℃	-	±0.6	-	mV/℃

Note: Dropout voltage is defined as the input voltage minus the output voltage that produces a 2% change in the output voltage from the value at V_{IN} = V_{OUT}+2V with a fixed load.

TX7540Hxx, +4.0V Output Type

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V_{IN}	Conditions				
V_{OUT}	Output Voltage	8.0V	I_{OUT}=10mA	3.880	4.000	4.120	V
I_{OUT}	Output Current	8.0V	-	80	-	-	mA
ΔV_{OUT}	Load Regulation	8.0V	1mA≤I_{OUT}≤20mA	-	60	100	mV
V_{DIF}	Voltage Drop(Note)	-	I_{OUT}=1mA, ΔV_{OUT}=2%	-	100	-	mV
ISS	Current Consumption	8.0V	No load	-	2.5	5.0	μA
$\frac{V_{OUT}}{V_{IN} \quad V_{OUT}}$	Line Regulation	-	5.0V≤V_{IN}≤24V I_{OUT}=1mA	-	0.2	-	%/V
V_{IN}	Input Voltage	-	-	-	-	32	V
$\frac{V_{OUT}}{Ta}$	Temperature Coefficient	8.0V	IOUT=10mA 0℃<Ta<70℃	-	±0.6	-	mV/℃

Note: Dropout voltage is defined as the input voltage minus the output voltage that produces a 2% change in the output voltage from the value at V_{IN} = V_{OUT}+2V with a fixed load.

TX7544Hxx, +4.4V Output Type

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V_{IN}	Conditions				
V_{OUT}	Output Voltage	8V	I_{OUT}=10mA	4.268	4.400	4.532	V
I_{OUT}	Output Current	8V	-	80	-	-	mA
ΔV_{OUT}	Load Regulation	8V	1mA≤I_{OUT}≤20mA	-	60	100	mV
V_{DIF}	Voltage Drop(Note)	-	I_{OUT}=1mA, ΔV_{OUT}=2%	-	100	-	mV
ISS	Current Consumption	8V	No load	-	2.5	5.0	μA

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$\frac{V_{OUT}}{V_{IN} \quad V_{OUT}}$	Line Regulation	-	5.4V≤V_{IN}≤24V I_{OUT}=1mA	-	0.2	-	%/V
V_{IN}	Input Voltage	-	-	-	-	32	V
$\frac{V_{OUT}}{Ta}$	Temperature Coefficient	8V	IOUT=10mA 0℃<Ta<70℃	-	±0.7	-	mV/℃

Note: Dropout voltage is defined as the input voltage minus the output voltage that produces a 2% change in the output voltage from the value at V_{IN} = V_{OUT}+2V with a fixed load.

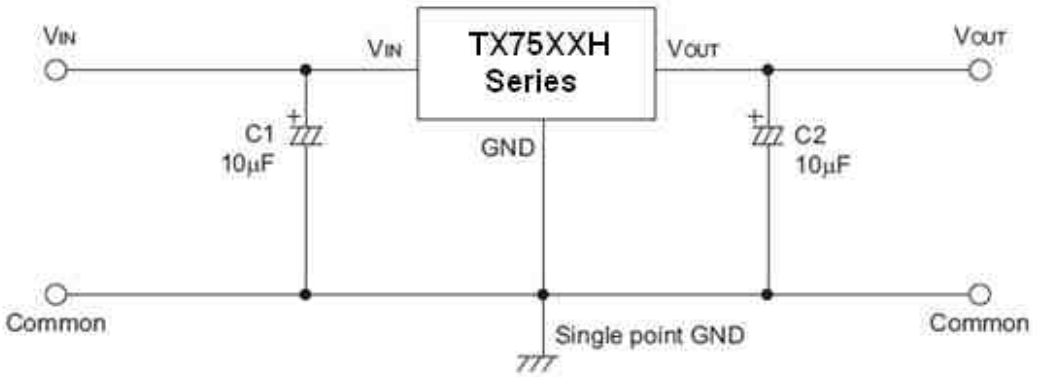
TX7550Hxx, +5.0V Output Type

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V_{IN}	Conditions				
V_{OUT}	Output Voltage	8V	I_{OUT}=10mA	4.85	5.00	5.15	V
I_{OUT}	Output Current	8V	-	100	-	-	mA
ΔV_{OUT}	Load Regulation	8V	1mA≤I_{OUT}≤20mA	-	60	100	mV
V_{DIF}	Voltage Drop(Note)	-	I_{OUT}=1mA, ΔV_{OUT}=2%	-	100	-	mV
ISS	Current Consumption	8V	No load	-	2.5	5.0	μA
$\frac{V_{OUT}}{V_{IN} \quad V_{OUT}}$	Line Regulation	-	6V≤V_{IN}≤24V I_{OUT}=1mA	-	0.2	-	%/V
V_{IN}	Input Voltage	-	-	-	-	32	V
$\frac{V_{OUT}}{Ta}$	Temperature Coefficient	8V	IOUT=10mA 0℃<Ta<70℃	-	±0.75	-	mV/℃

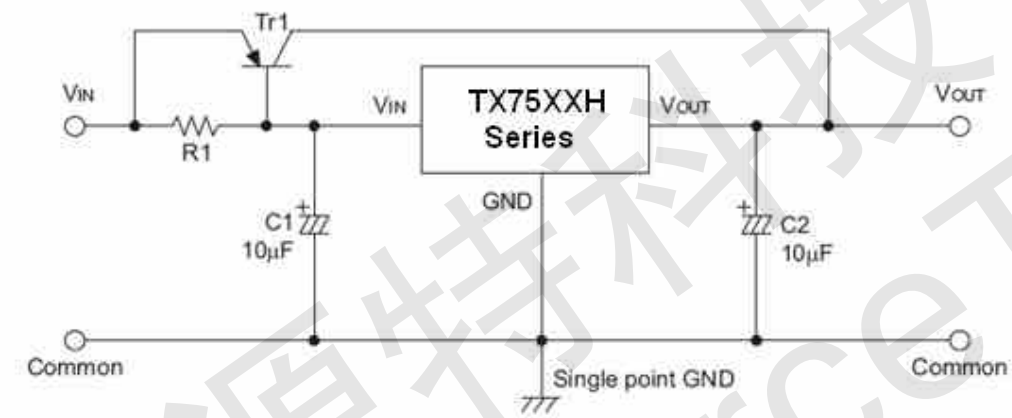
Note: Dropout voltage is defined as the input voltage minus the output voltage that produces a 2% change in the output voltage from the value at V_{IN} = V_{OUT}+2V with a fixed load.

Application Circuits

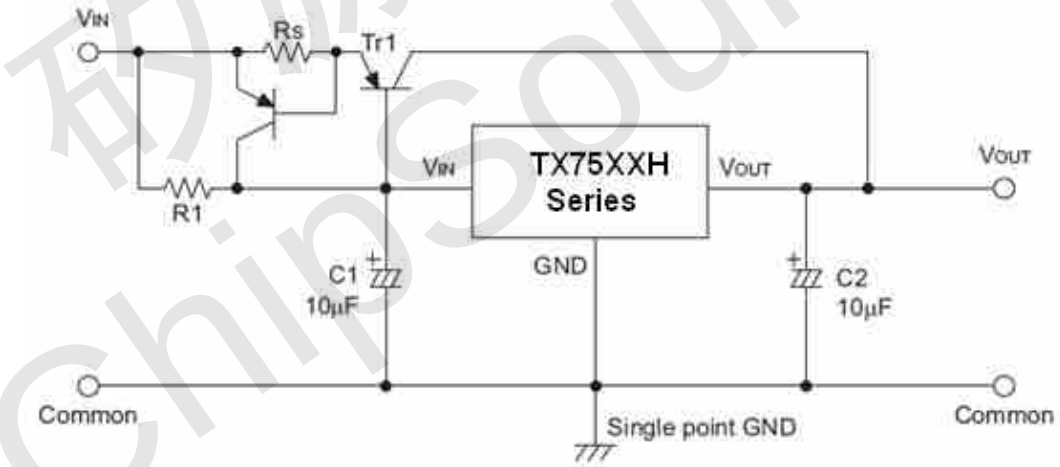
Basic Circuits



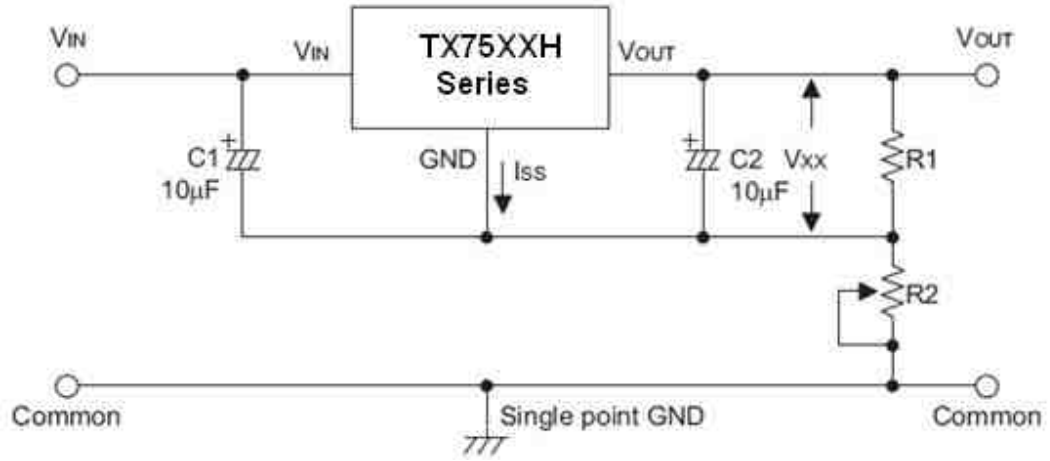
High Output Current Positive Voltage Regulator



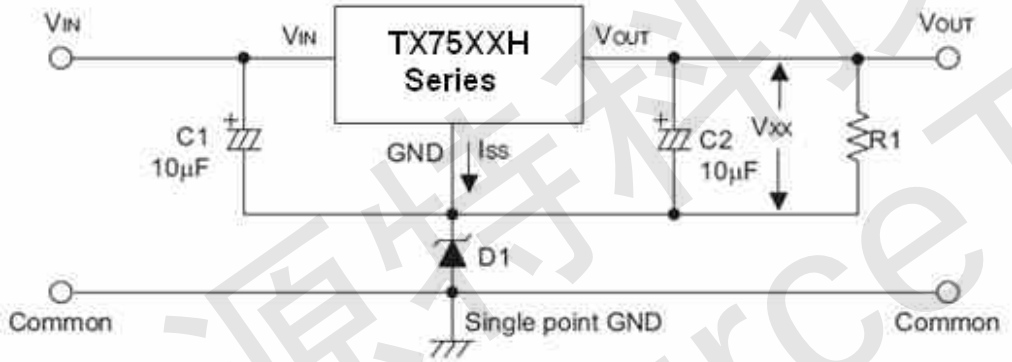
Short-Circuit Protection by Tr1



Circuit for Increasing Output Voltage

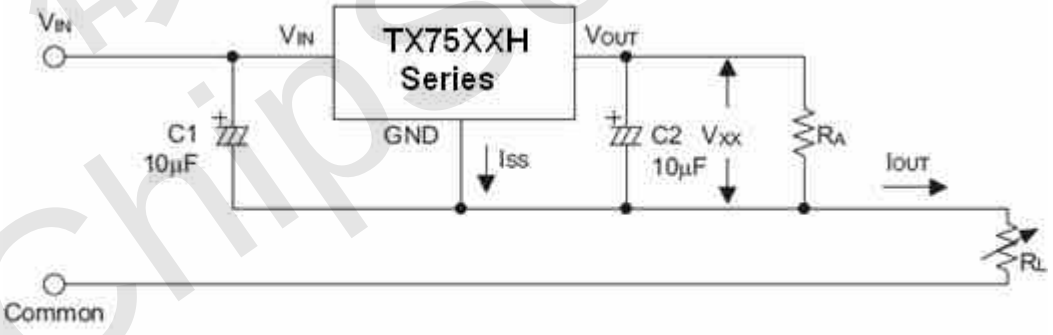


Circuit for Increasing Output Voltage



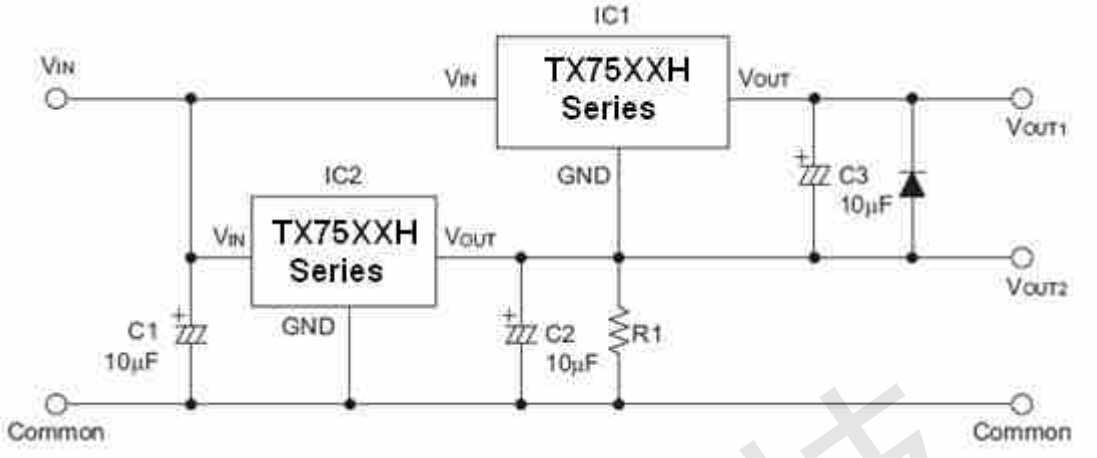
$V_{OUT}=V_{XX}+V_{D1}$

Constant Current Regulator



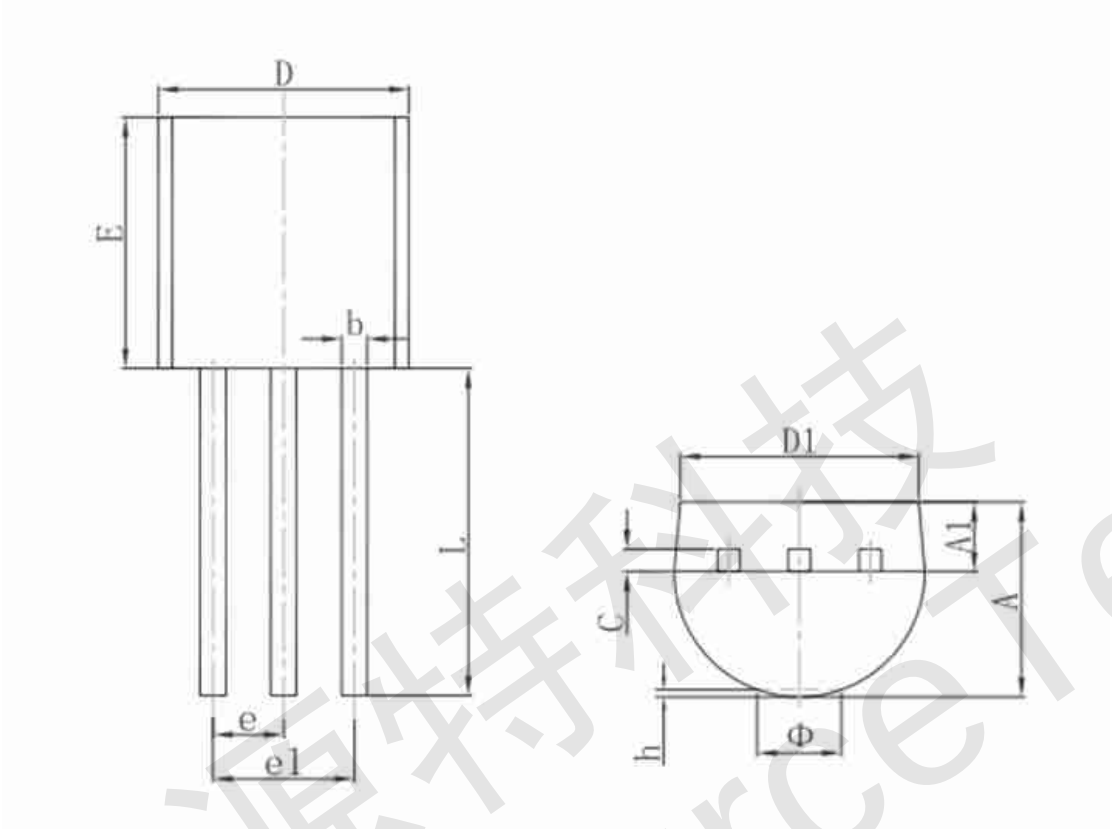
$$I_{OUT} = \frac{V_{XX}}{R_A} + I_{SS}$$

Dual Supply



Package Information

3-pin TO92 Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP.		0.050 TYP.	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

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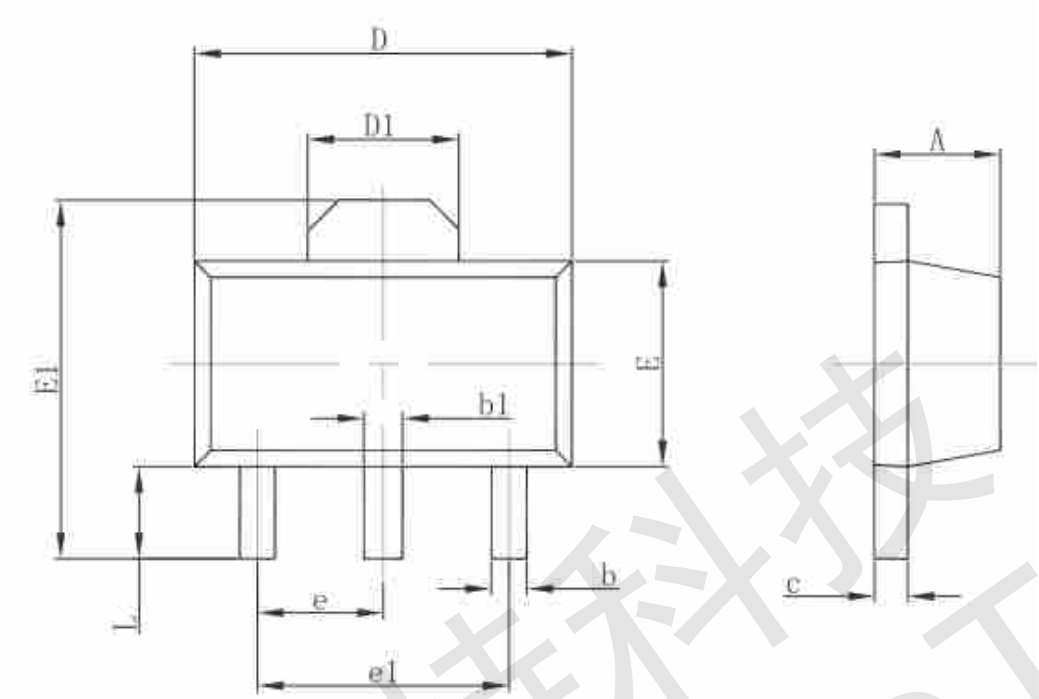
3-pin SOT89 Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF.		0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP.		0.060 TYP.	
e1	3.000 TYP.		0.118 TYP.	
L	0.900	1.200	0.035	0.047

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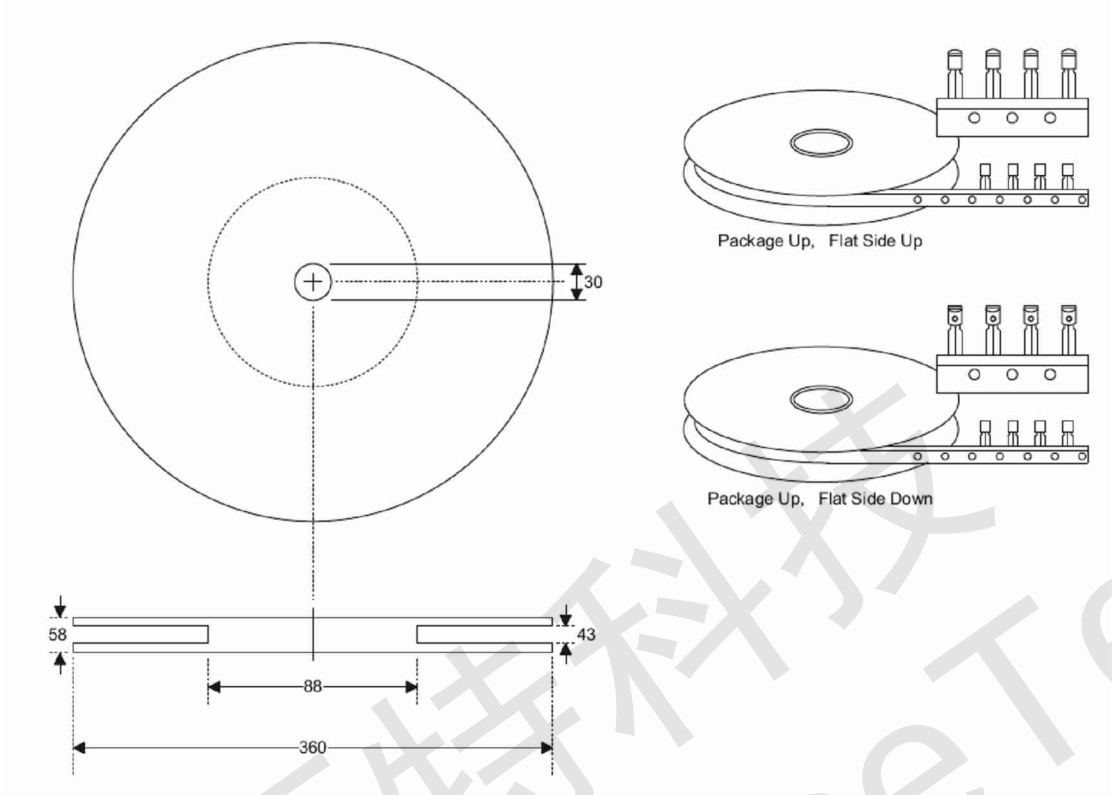
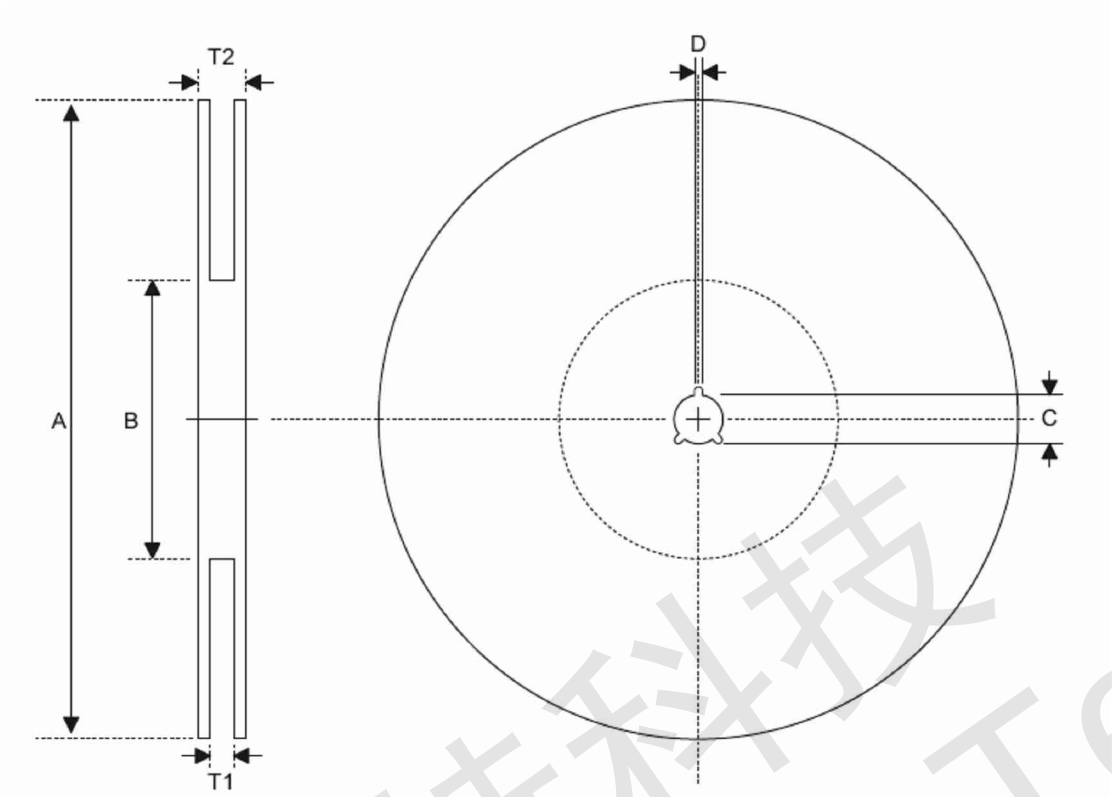
Product Tape and Reel Specifications

3-pin TO92 Reel Dimensions (Unit: mm)



Reel Dimensions



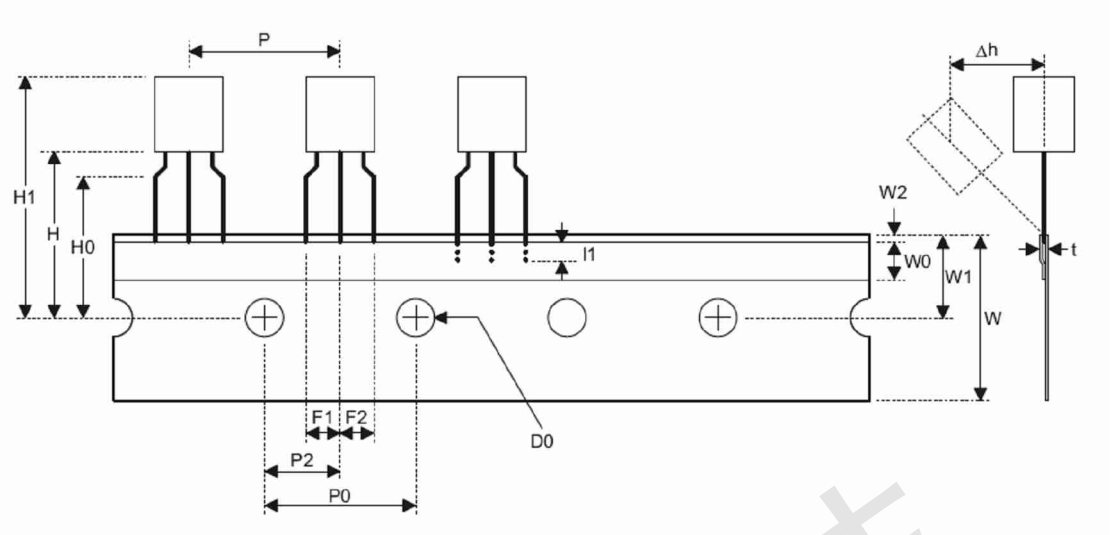
SOT89

Symbol	Description	Dimensions in mm
A	Reel Outer Diameter	180.0±1.0
B	Reel Inner Diameter	62.0±1.5
C	Spindle Hole Diameter	$12.75^{+0.15/-0.00}$
D	Key Slit Width	1.90±0.15
T1	Space Between Flange	$12.4^{+0.2/-0.00}$
T2	Reel Thickness	$17.0^{+0.0/-0.4}$

SOT23-5

Symbol	Description	Dimensions in mm
A	Reel Outer Diameter	178.0±1.0
B	Reel Inner Diameter	62.0±1.0
C	Spindle Hole Diameter	13.0±0.2
D	Key Slit Width	2.50±0.25
T1	Space Between Flange	$8.4^{+1.5/-0.0}$
T2	Reel Thickness	$11.4^{+1.5/-0.0}$

Carrier Tape Dimensions



TO92

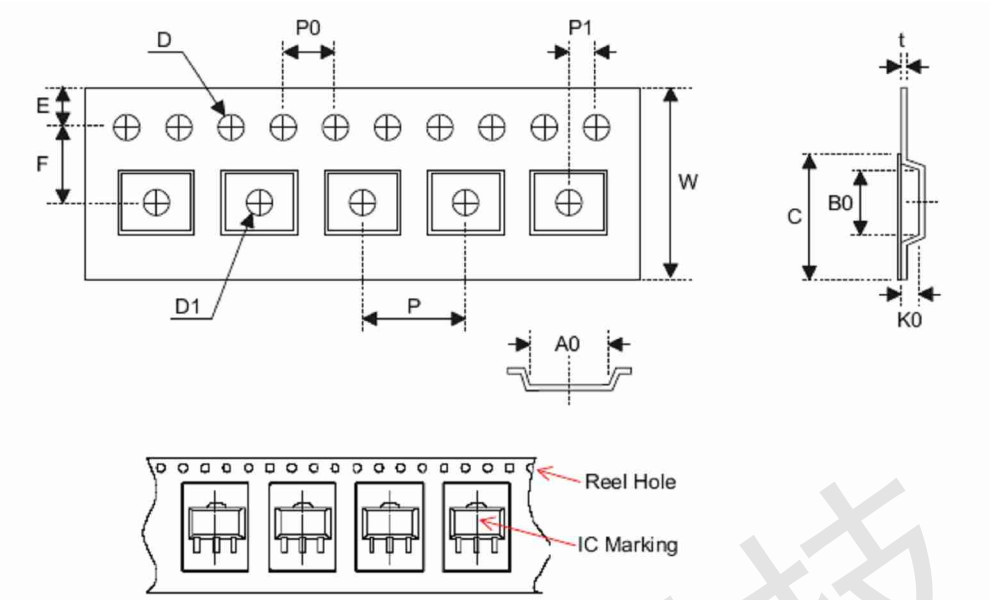
Symbol	Description	Dimensions in mm
I1	Taped Lead Length	(2.5)
P	Component Pitch	12.7±1.0
P_0	Perforation Pitch	12.7±0.3
P_2	Component to Perforation (Length Direction)	6.35±0.40
F_1	Lead Spread	$2.5^{+0.4/-0.1}$
F_2	Lead Spread	$2.5^{+0.4/-0.1}$
Δh	Component Alignment	0.0±0.1
W	Carrier Tape Width	$18.0^{+1.0/-0.5}$
W_0	Hold-down Tape Width	6.0±0.5
W_1	Perforation Position	9.0±0.5
W_2	Hold-down Tape Position	(0.5)
H_0	Lead Clinch Height	16.0±0.5
H_1	Component Height	Less than 24.7
D_0	Perforation Diameter	4.0±0.2
t	Taped Lead Thickness	0.7±0.2
H	Component Base Height	19.0±0.5

Note: Thickness less than 0.38_0.05mm~0.5mm

P0 Accumulated pitch tolerance: _1mm/20pitches.

( ) Bracketed figures are for consultation only

Carrier Tape Dimensions



SOT89

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	$12.0^{+0.3/-0.1}$
P	Cavity Pitch	8.0±0.1
E	Perforation Position	1.75±0.10
F	Cavity to Perforation (Width Direction)	5.50±0.05
D	Perforation Diameter	$1.5^{+0.1/-0.0}$
D1	Cavity Hole Diameter	$1.5^{+0.1/-0.0}$
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	4.8±0.1
B0	Cavity Width	4.5±0.1
K0	Cavity Depth	1.8±0.1
t	Carrier Tape Thickness	0.300±0.013
C	Cover Tape Width	9.3±0.1

SOT23-5

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	8.0±0.3
P	Cavity Pitch	4.0±0.1
E	Perforation Position	1.75±0.10
F	Cavity to Perforation (Width Direction)	3.50±0.05
D	Perforation Diameter	$1.5^{+0.1/-0.0}$
D1	Cavity Hole Diameter	$1.5^{+0.1/-0.0}$
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.00±0.05
A0	Cavity Length	3.15±0.10
B0	Cavity Width	3.2±0.1
K0	Cavity Depth	1.4±0.1
t	Carrier Tape Thickness	0.20±0.03
C	Cover Tape Width	5.3±0.1